



APPLICATION DATA SHEET

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| Title of Invention | [MULTI-LEVEL MEMORY CELL AND FABRICATING METHOD THEREOF] | |
| Application Type: regular, utility Attorney Docket Number: 11039-US-PA | | |
| Correspondence address: Customer Number: 31561 *31561* | | |
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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.